PN Series

Voltage output type photo sensor

- Built in the reverse connection of power protecting circuit and built in the output break protecting circuit.
- · Operation LED attached
- · Sensitivity adjusting volume attached
- · L.ON/D.ON selection by the external wire



Specification

Model		PN-T3	PN-M1	PN-R02	
Sensing method		Through beam	Retro reflection	Diffuse reflection	
Sensing distance		3 m	0.1 - 1 m	200 mm	
Sensing object		Opaque object above Ø8 mm	Opaque object above Ø48 mm	White paper with no gloss 200 × 200	
Power supply voltage		12 - 24 V DC, ± 10 %			
Current consumption	Emitter	20 mA DC	max 30 mA DC		
	Receiver	18 mA DC			
Control	output	NPN voltage output, Less than 200 mA (Load voltage: 30 V DC)		oltage: 30 V DC)	
Output	action	Selection of L. ON/D. ON b	y the control line (Through bea	am is only with the receiver)	
Response time		max 3 ms			
Hysteresis			less than 20% of the sensing distance		
Light source (wave length)		Infrared lightening LED (850 nm)			
LED		Control output indicator: Red LED (But emitter of the through beam indicates the power with red LED)			
Sensitivity adjustment		By the sensitivity adjusting volume (Exclude the emitter of through beam type)			
Protective circuit		power reverse connection protecting circuit and output break protecting circuit			
Ambient illumination		Sunlight: max 11,000 Lux, incandescent lamp: max 3,000 Lux			
Ambient temperature		-10 \sim 60 °C(surrounding storage temperature : -25 \sim 70 °C)			
Ambient humidity		$35\sim85$ % RH (With no condensation)			
Protective structure		IP 66 (IEC)			
Insulation resistance		min 20 MΩ(500 V DC, between the code and case)			
Dielectric strength		1,000 V AC, for 1 min			
Vibration resistance		10 - 55 Hz double amplitude: 1.5 mm, for 2 hours each in X, Y and Z direction			
Shock resistance		500 %, 3 times each in X, Y and Z directions			
Connection method		Code extended type 1.5 m			
Material		Case and lens : PC			
Weight		Approx. 250 g (included the weight of box)	Approx. 150 g (included the weight of box)	Approx. 100 g (included the weight of box)	

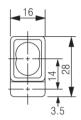
(Note 1) The sensing distance can be varied depending on the size, surface condition, glossy, non-glossy of the sensing object

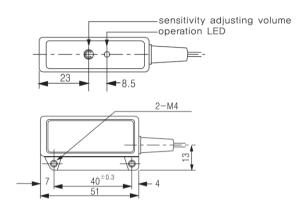
(Note 2) PN-TL3 is emitter and PN-TR3 is receiver when it is through beam type



Oimension (unit : mm)

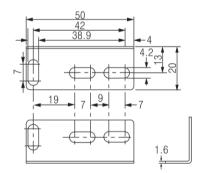
■ Dimension of external part



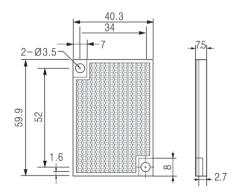


■ Product holder





■ Mirror (HY-M5)



Installation method

■ Diffuse reflection type (PN-R02)

- Generally it is used with the max sensitivity setting (PN-RD1) but it may be affected by the front side
 wall, pole and etc so please be cautious when adjusting.
- · Increasing the sensitivity too much may end up with malfunction so please be cautious
- (1) With the sensing object in the position, increase the volume gradually from the min sensitivity to the state when operation LED becomes ON and that position will be referred as point @.
- (2) With the sensing object not in the position, decrease the volume gradually from the max to the state when operation LED becomes OFF and that position will be referred as point (a).
- (3) The position halfway between point (a) and (b) is the most suitable position

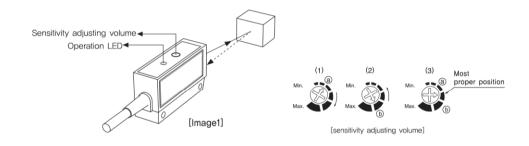
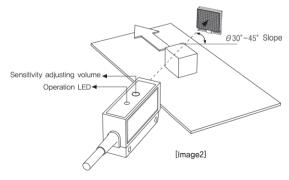


Photo Sensor

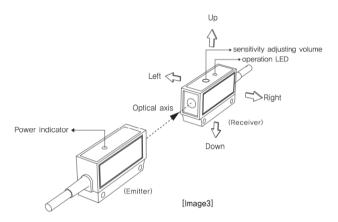
■ Retro reflection type (PN-M1)

- Install the sensor and mirror face to face. After that, adjust the position of mirror to up, down, left and right direction and confirm the range where operation LED light becomes turned OFF. Install it at the center of position where the light became turned OFF.
- Adjust the sensitivity adjustment volume at the most suitable position according to the sensing range, sensing object and etc.
- When installing more than 1 sensor, please keep the distance (gap) more than 30cm due to the possibility of malfunction occurrence.
- When the sensing object is glossy or highly reflective, please install at an angle of 30~45degree
 according to the moving direction of sensing object in order to prevent malfonction from occurring
 [refer to the image 2 provided below]



■ Through beam type (PN-T3)

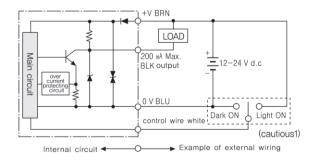
- Install the emitter and receiver face to face in the straight line and check for the proper wiring. After finishing confirmation, supply in the power.
- Fix either the emitter or receiver and check for the range where operation indicator becomes turned OFF by controlling the others in the direction of up, down, left and right. After finishing the confirmation, place it in the middle and fix it,
- · After finishing the installation, place sensing object at the optic part and check whether it is operated or not,
- If the sensing objects are semitransparent or too small (Less than 8 mm) then there is possibility that sensor will not detect any objects because they just pass through so please be cautious





Output circuit diagram

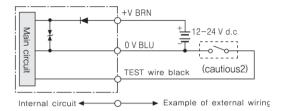
Receiver of diffuse reflection type, retro reflection type, and through beam type



(Cautious 1) Display the Light ON/Dark ON mode selection wiring method

Light ON: Open or connect the control wire to +V Dark ON: When connecting the control wire to 0V

■ Emitter of through beam type



Note 2)

- ① Transmitting LED and power indicator become OFF when connecting to the TEST wire 0V. (TEST operation state) Transmitting LED and power indicator become ON when connecting to the TEST wire 0V. (Normal operation state)
- 2 Maintain the TEST wire in an OFF state when operating
- 3 Insulated the wires that are not used.

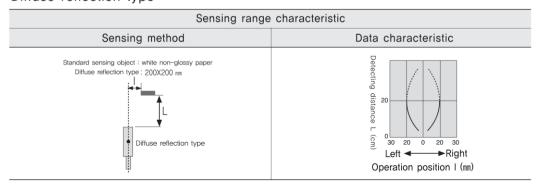
Operation chart

Detect	ion status	L-ON D-ON
	TR output and	
Light ON	L.ON indicator	ON I I I I I I I I I I I I I I I I I I I
	(red LED)	OFF
	TR output and	
Dark ON	D.ON indicator	ON CONTRACTOR OF THE CONTRACTO
	(red LED)	OFF

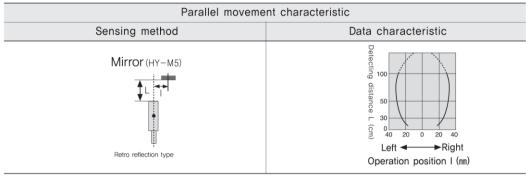


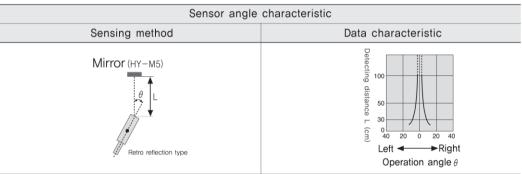
Graphic characteristic

Diffuse reflection type



■ Retro reflection type characteristic





■ Through beam characteristic

